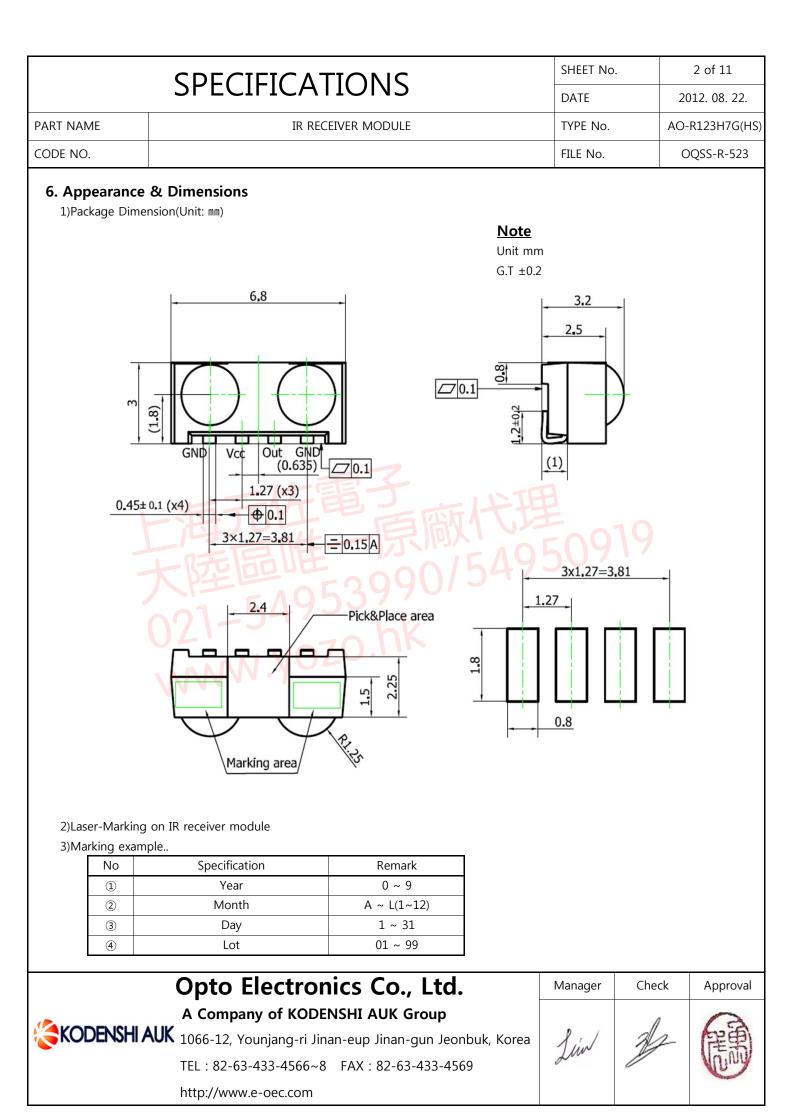
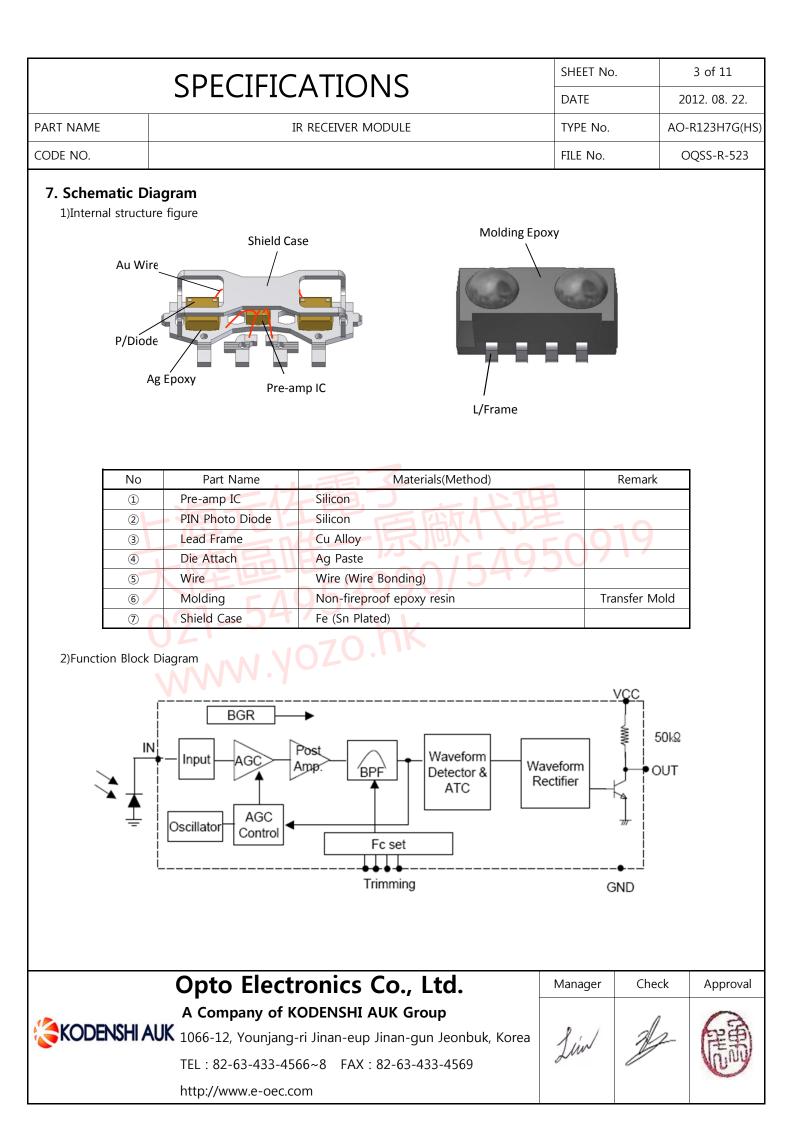
		SHEET No	).	1 of 11
	SPECIFICATIONS	DATE	2	012. 08. 22.
PART NAME	IR RECEIVER MODULE	TYPE No.	AO	-R123H7G(HS)
CODE NO.		FILE No.	C	DQSS-R-523
<b>1. Application</b> This Specificati	on is applied to inspection and approval of the IR Receiver Module for TV	, DVD, STB et	с	
The PIN Photo The module ha	niniaturized receiver for infrared remote control system. diode and preamplifier are assembled on lead frame. The epoxy pacakge i as excellent performance even in disturbed ambient light application and p crolled output pulses.	0		
<ul> <li>3)Low current of 4)Band pass file</li> <li>5)Epoxy IR filter</li> <li>6)Maximum internal filter</li> <li>7)Internal filter</li> <li>8)Internal pullet</li> <li>4. Absolute N</li> <li>1)Supply voltage</li> <li>2)Supply current</li> <li>3)Output current</li> <li>4)Operating ternal</li> <li>5)Storage tempe</li> <li>6)Reflow solder</li> <li>5. Cautions</li> <li>1)Store and us</li> <li>2)Store and us</li> <li>3)In order to persoldering iront</li> <li>4)The ripple not</li> <li>Thus, in order</li> <li>5)When a disture</li> </ul>	ing supply voltage : 2.7V ~ 6.0V consumption : 3.0V(0.4mA), 5.0V(0.5mA) ter center frequency : 37.9KHz er characteristic : 940nm terference safety against optical and electrical disturbance for a high frequency lighting fluorescent lamp up output : 50kΩ <b>Iaximum Ratings</b> ge : 0 ~ 7.0V mt : 0 ~ 3.0mA	<sup>r</sup> module. between Vcc		
(b)Continu	nt(Ex. From tungsten lamp or sunlight) uous signal at center frequency or any other frequency from fluorescent lamps with electronic ballact with high or law modulatio	n		
©Signals	from fluorescent lamps with electronic ballast with high or low modulatio		1	
	Opto Electronics Co., Ltd.	Manager	Check	Approval
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	SPECIFICATIONS	DATE		2012. 08. 22.
PART NAME	IR RECEIVER MODULE	TYPE No.	AC	D-R123H7G(HS)
CODE NO.		FILE No.		OQSS-R-523
The function of Photo current IC called "Input The DC part is followed by a The final evalue The "Automat the influences optical burst of The detail of " (1)Input Block (2)AGC-Amplif The detail of " (3)Post-Amplif The most go (4)Band Pass F It is designe on current of (5)AGC Contro It reacts to t The AGC set The AGC do The AGC dis length and of (6)Waveform F Compare wir burst signal, signal size. T (7)Waveform F The integrat It needs sev output is trig	ption of Function Block Diagram of the IC is described with above function block diagram. generated by infrared radiation burst signal equivalently goes through th ut Block". s separated in the coupling cap of the each amplifier and AC signal pass in n automatic gain control amplifier, a post amplifier and a band pass filter uation is done by a waveform detector & ATC, waveform rectifier stage. ic Gain Control" is responsible for the dynamic control if stable working p of disturbing sources. The digital output signal, which is an envelope sig without the carrier frequency, has active low polarity. the each block is as below. reacts to the photo diode as a frequency-dependent load resistance. fier generates most of the voltage gain of the whole circuitry where by th ier generates a signal gain to be fit to band pass filter input by limiting s to the voltage gain is decided by a load resistance and emitter resistance. filter is an important part of the circuit to get a good performance in dist d to achieve a specified frequency response and exhibit different character alue of each element.	to a pre-ample point to supprimal of the incomposition ignal amplification ignal amplification urbed ambient eristics dependent ambient light t pulse. arks are burst utput and detent filter output putput signals. oltage. aded and the	ifier ess oming n. de. <b>19</b> ding	
	Opto Electronics Co., Ltd.	Manager	Check	Approval
<b>KODENSHI</b>	A Company of KODENSHI AUK Group AUK 1066-12, Younjang-ri Jinan-eup Jinan-gun Jeonbuk, Korea TEL : 82-63-433-4566~8 FAX : 82-63-433-4569 http://www.e-oec.com	Lim	de la	E

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PART NAME	IR RECEIVER MODULE	TYPE No.	AO-R123H7G(HS)
CODE NO.		FILE No.	OQSS-R-523

### 8. Electro-Optical Characteristics (At 25°C unless otherwise notes)

## 1)Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply Voltage	Vcc	0 ~ 6.0	V
Output Current	lout	0 ~ 2.5	mA
Operating Temperature	Topr	-20 ~ +80	°C
Storage Temperature	Tstg	-30 ~ +85	°C
Soldering Temperature(*1)	Tsol	260, t<5sec	°C
Reflow Soldering Temperature(*1)	Tsol	260, t<10sec	°C
Moisture Sensitive Level(*2)		Level 5a (≤30°C/60%RH 24Hour	s)

#### (\*1)Pb Free Solder

(\*2)JEDEC Standard J-STD-020C

#### 2)Recommended operating Conditions

Parameter	Symbol	Rating	Unit
Operating Voltage	Vcc	2.7 ~ 6.0	V
Input Frequency	fin	36 ~ 40	kHz

# 3)Elector\_Optical Characteristics [Vcc=5.0V, Vcc=3.0V]

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Supply Voltage	Vcc		2.7		5.5	V
Supply Current		No Input Vcc=5V	0.2	0.5	0.7	mA
supply current 54	Icc	Signal Vcc=3V		0.45		IIIA
Peak Wavelength (%1)	λр	hk	-	940	-	nm
B.P.F Center Frequency (%2)	fo		-	37.9	-	kHz
High Level Output Voltage (※1)	V <sub>OH</sub>	30cm over the ray axis	4.5	5.0	-	V
Low Level Output Voltage (%1)	V <sub>OL</sub>	Soull over the ray axis	-	0.2	0.4	V
High Level Output Pulse Width (※1)	t <sub>WH</sub>	Burst Wave = $600\mu$ s	400	-	800	μs
Low Level Output Pulse Width (X1)	t <sub>WL</sub>	Period = $1.2$ ms	400	-	800	μs
Arrival Dictorso (X1)	D	±0°	20	-	-	m
Arrival Distance (※1)	D	±30°	15	-	-	m
Output Form		Active	Low Output	t		

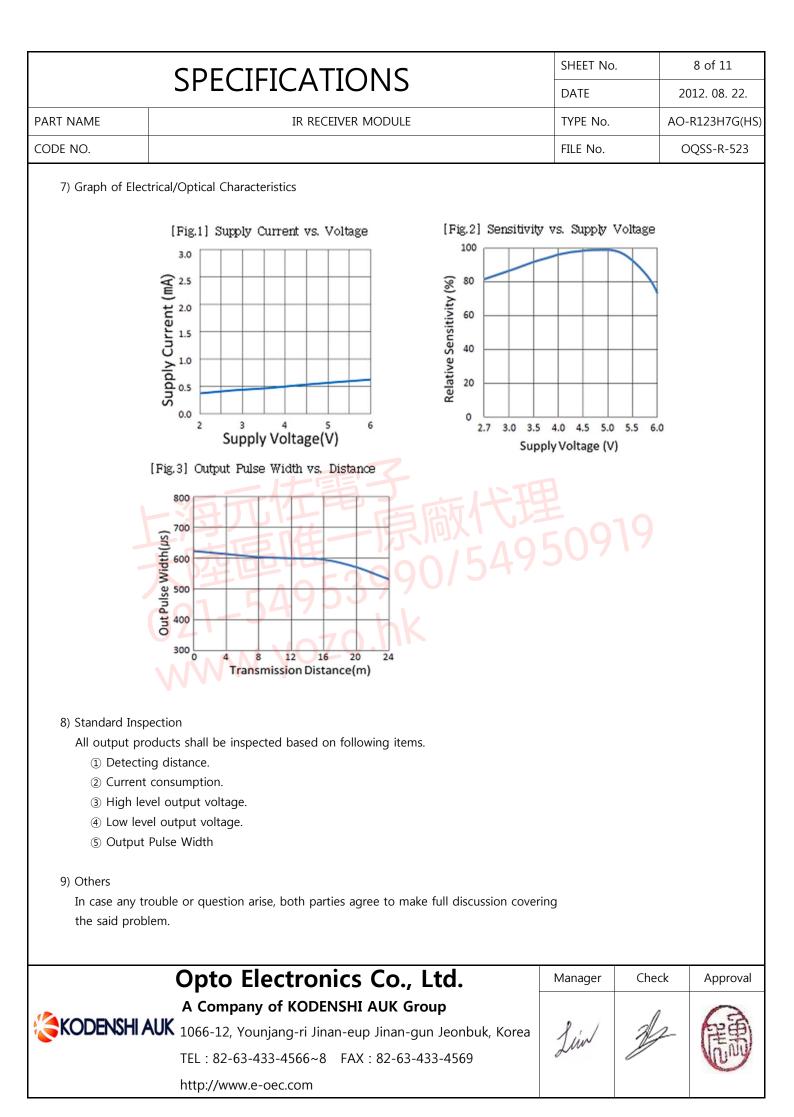
× 1. 600/600μs burst wave is transmitted by standard(Fig.2, Fig.3) transmitter. However, it measured after the initial transmission pulse is 10(60ms) pulse.

% 2. The following band pass frequencies are available.(36.7kHz/37.9kHz/40kHz) Carrier frequencies adjusted by zener-diode fusing method.



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PART NAME	IR RECEIVER MODULE	TYPE No.	AO-	R123H7G(HS)
CODE NO.		FILE No.	С	QSS-R-523
<ul> <li>4) Measurement</li> <li>① Fig.1 Burst</li> <li>※ LCD Dimming have</li> <li>1) Data word length =</li> <li>2) tpause = Min. 59ms</li> <li>3) Duty(Σtburst /T) = 1</li> </ul>	wave, Output wave $ \begin{array}{c} \hline Transmitting time for 1 block:T \\ \hline Data word \\ \hline tpause \\ $			
When sta	Standard transmitter	become Io=5uA	9 p-p	
	e measurement condition Fig.2. (The radiant intensity of standard transmit	ter : 50mW/sr)		
HP-5FR4	: standard photodiode has short current Isc=32uA at E=1000(lx)			
③ Fig.3 Test	Condition of Arrival Distance			
	Receiver AO-R123C6H-HS(T) Standard transmitter Effective distance: L			
	( $\Theta$ : Indicates horizontal and Vertical t light source : Detecting surface's illumination shall be 100Lux under ordi	nary white		
	Opto Electronics Co., Ltd.	Manager	Check	Approval
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	SPECIFICATIONS	DATE		2012. 08. 22.
PART NAME	IR RECEIVER MODULE	TYPE No.	AC	D-R123H7G(HS)
CODE NO.		FILE No.		OQSS-R-523
However th Some exan a. Signal b. Conti	uppression turbance signal is applied to the AO-R123H7G(HS)., Series, It can receive the sensitivity is reduced to that level that no unexpected pulses will occu aples for such disturbance signals which are suppressed by the AO-R123 s from fluorescent lamps with electronic ballast (please refer to Fig.1) nuous signal at 37.9kHz or at any other frequency ht (from tungsten lamp or sunlight)	r.		
There will b according t	t Lamp with Modulation] The signals shown in [Fig. 1] come from a fluore electronic ballast Which is operated at 60 Hz and A different kind of disturbance signal is caused by lamps with electronic ballast. Typically the oscillating frequency of the optical d signal of such lamps is in the range between 20kH This frequency is twice of the electrical oscillating of the driver circuit in the lamp ballast. All AO-R123H7G(HS). Series IR receiver modules of disturbance signals efficiently be unexpected output pulses due to such lamps. However, sensitivity will o the strength of the disturbance signal. More critical are the electronic of the oscillating amplitude are more critical	120Hz power lin fluorescent isturbance Iz and 50kHz. frequency an suppress suc be reduced	ine frequer	ncy.
peripheral p Using the fi resistor, cor 2 The ripple Thus, in orc Vcc and GN 3 Store and 4 Store and 5 In order to iron are cor 6 In order to shall be gro 7 Please use	use where there is no force causing transformation or change in quality. use where there is no extreme humidity. prevent damage from static electricity, make sure that the human body nected to ground before using. prevent electrostatic discharge of integrated circuit, human body and so	e receiver modu ponents such as ver module. $7\mu$ F) between and the solder oldering iron, et	ring	
<b>EXCODENSHI</b> A	Opto Electronics Co., Ltd. A Company of KODENSHI AUK Group UK 1066-12, Younjang-ri Jinan-eup Jinan-gun Jeonbuk, Korea TEL : 82-63-433-4566~8 FAX : 82-63-433-4569 http://www.e-oec.com	Manager Juin	Check	Approval



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PART NAME	IR RECEIVER MODULE	TYPE No.	AO-R123H7G(HS)
CODE NO.		FILE No.	OQSS-R-523

## 9. Reliability Test Item and Standard.

- 1) All output products shall satisfy below Reliability test items.
- 2) Related sampling quantity and acceptance/failure judgment standard accordance with MIL standard MIL-STD-833 is as listed below.

①Confidence Level: 90%
2LPTD: 10% / 20%

Test Item	Test Conditions	Judgment Standard	Fail@ Sample(n)
High Temp. Storage (※ 2)	Ta=+120°C, t=500HR's	VOH(Vcc=5V)	C=0/n=22
Low Temp. Storage (※ 2)	Ta=-30°C, t=500HR's	High level output voltage	C=0/n=22
High Temp. Bias (※ 1, ※ 2)	Ta=+85°C, t=500HR's	Low level output voltage	C=0/n=22
High Temp./High Hum.(※ 2)	Ta=+85°C, 90%RH, t=500HR's	VOL<0.4V Icc(Vcc=5.0V)	C=0/n=22
Temperature Cycle(X 2)	Ta=-20°C(0.5HR) to +85°C(0.5HR) 20 Cycle	Consumption Current Icc<1.5mA D(Vcc=5.0V) Arrival Distance: D>8m	C=0/n=22
P.C.T(% 2)	Ta=+121°C, 100%RH, P=2atm, t=4HR's		C=0/n=22
Solder Heat(% 2, % 5)	Ta=260±5°C, t=5s		C=0/n=11
Solder ability(% 5)	Solder Temp.: 260±5°C, t=5s Pb Free Solder: Sn/Cu	Leads shall be covered By solder more than 95%	C=0/n=11
	High Temp. Storage (% 2) Low Temp. Storage (% 2) High Temp. Bias (% 1, % 2) High Temp./High Hum.(% 2) Temperature Cycle(% 2) P.C.T(% 2) Solder Heat(% 2, % 5)	High Temp. Storage ( $\xee$ 2)Ta=+120°C, t=500HR'sLow Temp. Storage ( $\xee$ 2)Ta=-30°C, t=500HR'sHigh Temp. Bias ( $\xee$ 1, $\xee$ 2)Ta=+85°C, t=500HR'sHigh Temp./High Hum.( $\xee$ 2)Ta=+85°C, 90%RH, t=500HR'sTemperature Cycle( $\xee$ 2)Ta=+20°C(0.5HR) to +85°C(0.5HR) 20 CycleP.C.T( $\xee$ 2)Ta=+121°C, 100%RH, P=2atm, t=4HR'sSolder Heat( $\xee$ 2, $\xee$ 5)Ta=260±5°C, t=5sSolder ability( $\xee$ 5)Solder Temp.: 260±5°C, t=5s	High Temp. Storage (% 2)Ta=+120°C, t=500HR'sVOH(Vcc=5V)Low Temp. Storage (% 2)Ta=-30°C, t=500HR'sVOH->4.5VHigh Temp. Bias (% 1, % 2)Ta=+85°C, t=500HR'sLow level output voltage VOH>4.5VHigh Temp./High Hum.(% 2)Ta=+85°C, 90%RH, t=500HR'sLow level output voltage VOL<0.4V

%1. Supply voltage of load test is 5V.(Standard Jig of OEC)

\*2. Electro-optical characteristics shall be satisfied after leaving 2 hours in the normal condition.

- \*3. Temperature cycle test shall repeat above condition 20 times under no load.
- %4. The test devices shall be dropped three time on the hard wooden board from a height of 75cm.
- %5. For 5sec (after mounting on PCB with thickness of 1.6mm)

In case any trouble or question arises related to above test items, both parties agree to make full discussion and covering the said matters.



